

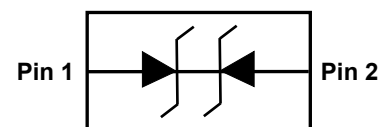
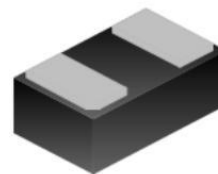
Description

The SXESDNC2FD24VB protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.

Feature

300W peak pulse power per line ($t_P = 8/20\mu s$)
DFN1006-2L package
Replacement for MLV(0402)
Bidirectional configurations
Response time is typically < 1ns
Low clamping voltage
RoHS compliant
Transient protection for data lines to
IEC61000-4-2(ESD) $\pm 20KV$ (air), $\pm 20KV$ (contact);
IEC61000-4-4 (EFT) 40A (5/50ns)

DFN1006-2L



Applications

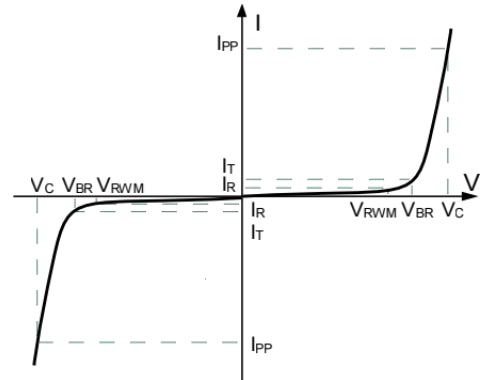
Cellular phones
Portable devices
Digital cameras
Power supplies

Mechanical Characteristics

Mounting position: Any
Qualified max reflow temperature: 260°C
Device meets MSL 1 requirements
DFN1006-2L without plating

Electronics Parameter

Symbol	Parameter
V_{RWM}	Peak Reverse Working Voltage
I_R	Reverse Leakage Current @ V_{RWM}
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_{PP}	Maximum Reverse Peak Pulse Current
V_C	Clamping Voltage @ I_{PP}
P_{PP}	Peak Pulse Power
C_J	Junction Capacitance
I_F	Forward Current
V_F	Forward Voltage @ I_F



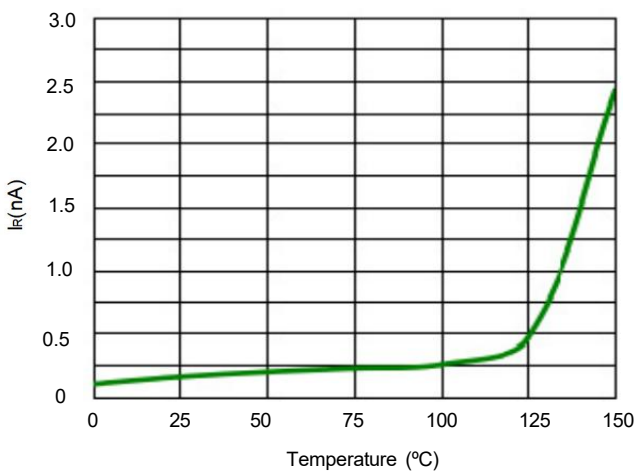
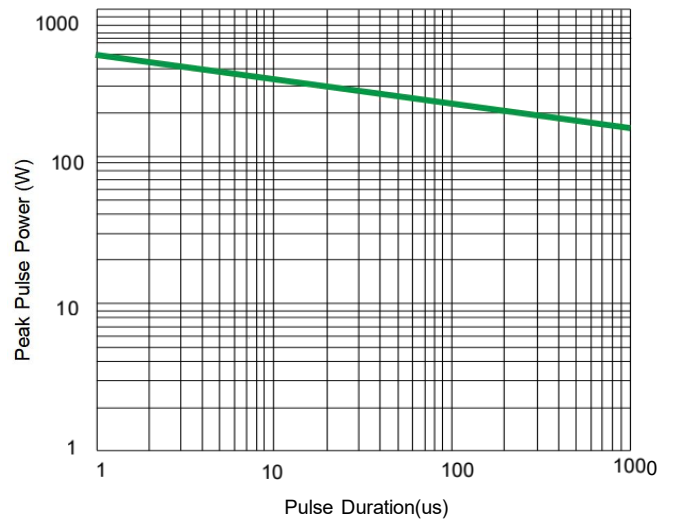
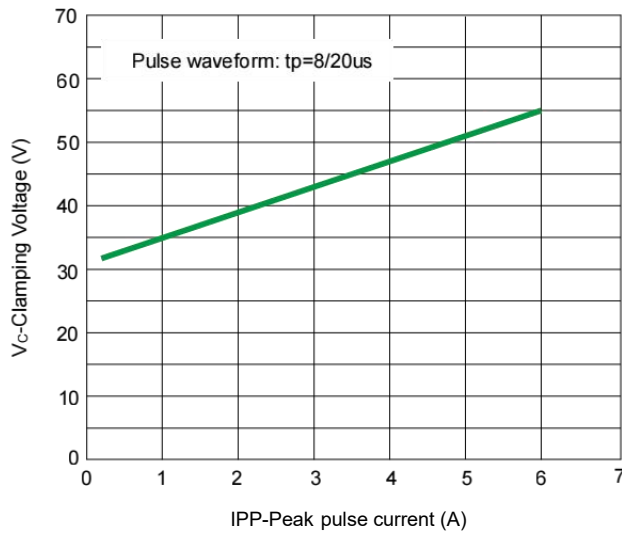
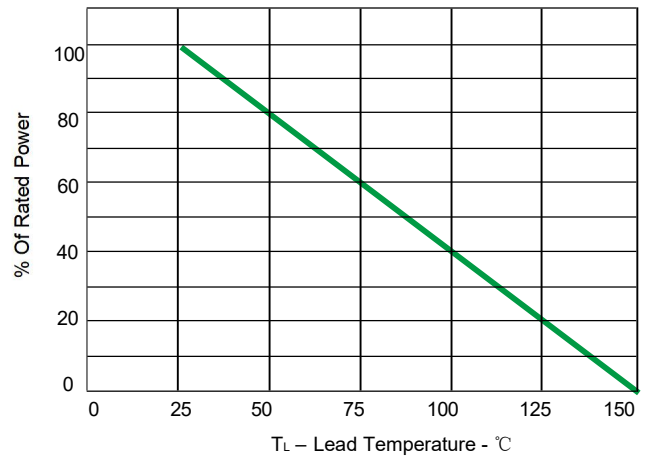
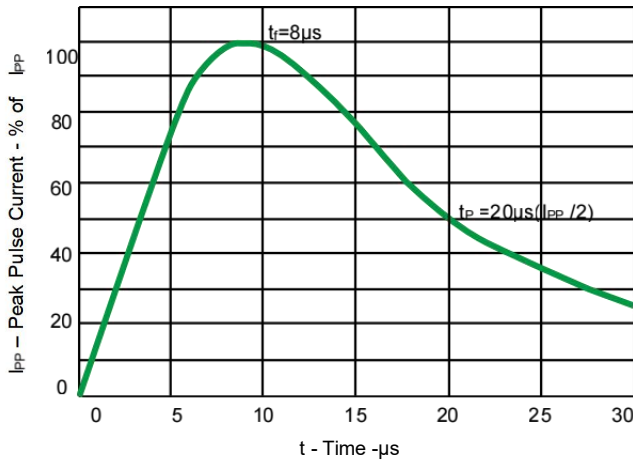
Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				24	V
Breakdown Voltage	V_{BR}	$I_T = 1\text{mA}$	25	27		V
Reverse Leakage Current	I_R	$V_{RWM} = 24\text{V}$ $T = 25^\circ\text{C}$			1.0	μA
Clamping Voltage	V_C	$I_{PP} = 1\text{A}$, $t_P = 8/20\mu\text{s}$		34	40	V
Clamping Voltage	V_C	$I_{PP} = 6\text{A}$, $t_P = 8/20\mu\text{s}$		55	60	V
Junction Capacitance	C_J	$V_R = 0\text{V}$ $f = 1\text{MHz}$		15	20	pF

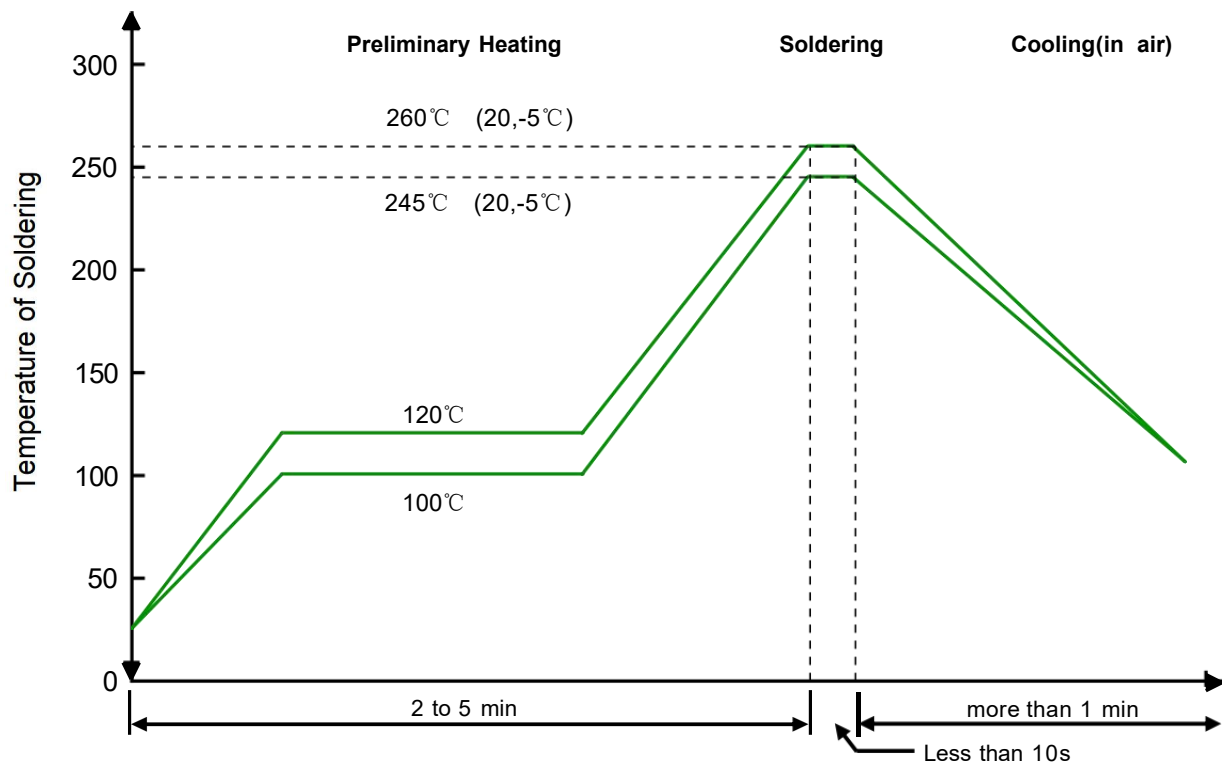
Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power ($t_P = 8/20\mu\text{s}$)	P_{PP}	300	W
Operating Temperature	T_J	-55 to 150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to 150	$^\circ\text{C}$

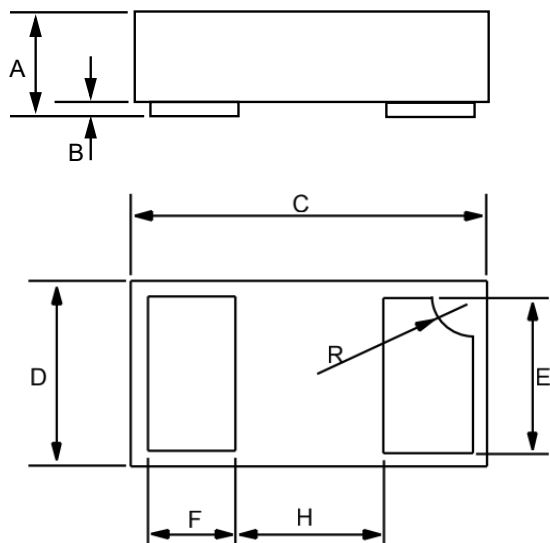
Typical Characteristics



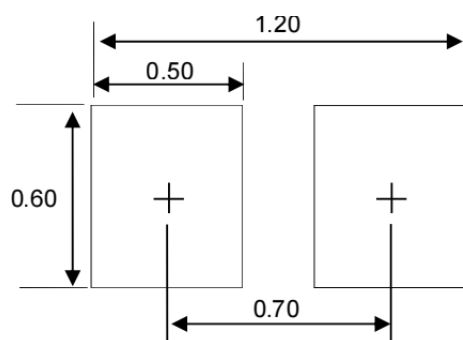
Solder Reflow Recommendation



Remark: Pb free for 260°C ; Pb for 245°C .

Product dimension (DFN1006-2L)


Dim	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.013	0.020	0.34	0.50
B	0.000	0.002	0.00	0.05
C	0.037	0.043	0.95	1.080
D	0.022	0.027	0.55	0.680
E	0.016	0.024	0.40	0.60
F	0.008	0.012	0.20	0.30
H	0.015Typ.		0.40Typ.	
R	0.001	0.005	0.05	0.15


Suggested PCB Layout

Unit:mm

Ordering information

Device	Package	Reel	Shipping
TAPING	DFN1006-2L (Pb-Free)	7"	10000 / Tape & Reel